

Technical Data Data Sheet N1458, Rev. - **Green Products**

STB4080C SCHOTTKY RECTIFIER

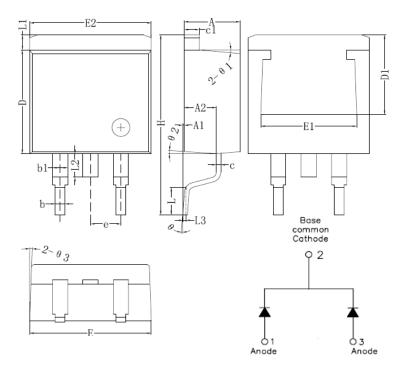
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150 °C TJ operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

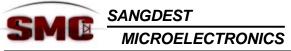
Mechanical Dimensions: In mm



Symbol	Dimensions in			
	millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4 °		
e3		4°		

$D^2 PAK$

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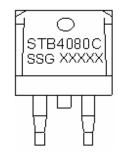


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Marking Diagram:



Where XXXXX is YYWWL

S T	= Device Type = Ultralow VF
В	= Package type
40	= Forward Current (40A)
80	= Reverse Voltage (80V)
С	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
STB4080C	D ² PAK	800pag / rool
	(Pb-Free)	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	80	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =105 °C rectangular wave form	40	А
Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	300	A



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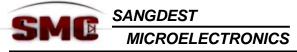
Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (per leg) *	V_{F1}	@ 10A, Pulse, T _J = 25 °C @ 20A, Pulse, T _J = 25 °C	0.54 0.69	0.60 0.75	V
	V_{F2}	@ 10A, Pulse, T _J = 25 °C @ 20A, Pulse, T _J = 125 °C	0.52 0.65	0.57 0.70	V
Reverse Current at DC condition (per leg)	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	0.02	1.0	mA
Reverse Current (per leg) *	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	14	75	mA
Junction Capacitance (per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	811	-	pF

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	2.0	°C/W
Approximate Weight	wt	-	1.85	g
Case Style		D ² PAK		



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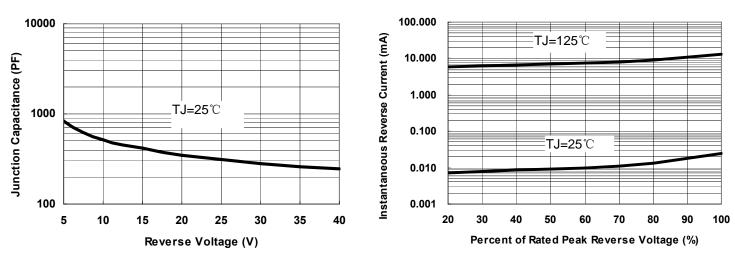


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

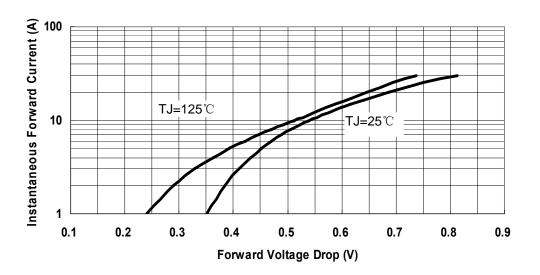
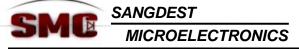


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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